

Supplementary Information

For

Epitaxy growth of MAPbBr_xCl_{3-x} single-crystalline perovskite films toward spectral selective detection in both broadband and narrowband range

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Keywords: epitaxial growth, mixed-halide perovskite, photoelectric characteristics, tunable spectral response, dual-mode detection

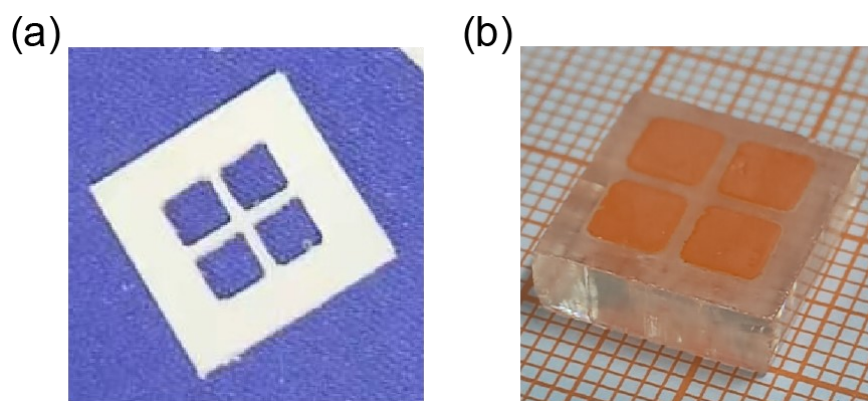


Figure S1 (a) Photograph of the used Teflon mould with a square of $15 \times 15 \text{ mm}^2$ and thickness of 1 mm. (b) Photograph of the epitaxial 2×2 MAPbBr₃ single-crystalline arrays on MAPbCl₃ crystals with single pixel area of $4 \times 4 \text{ mm}^2$.

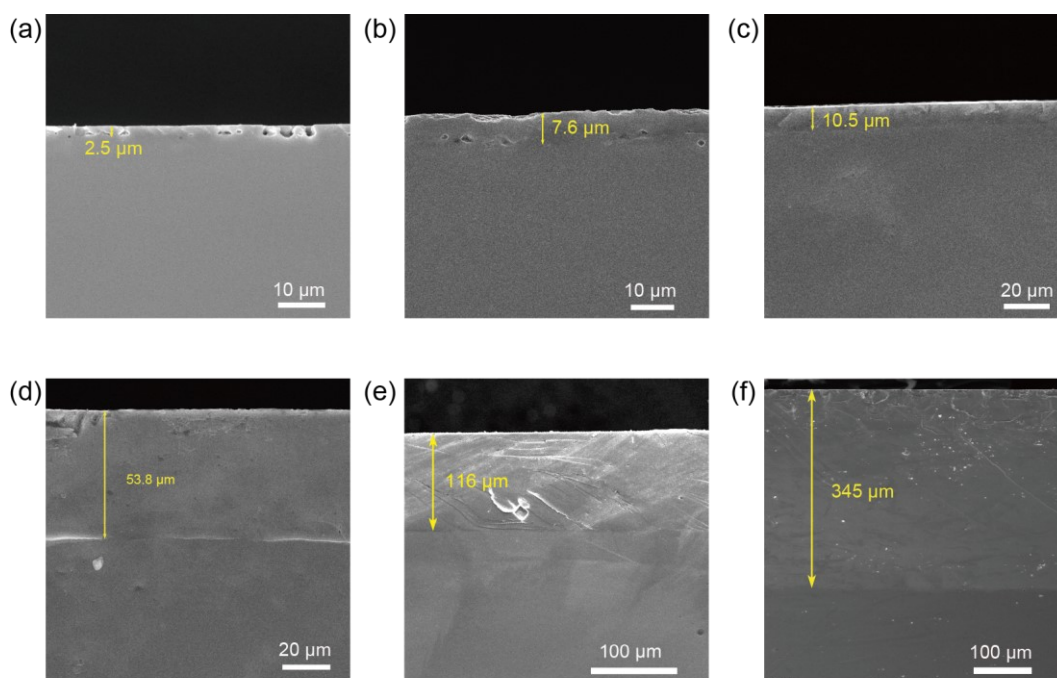


Figure S2 Cross-sectional SEM images of the formed heterojunction interfaces with the duration of MAPbCl₃ crystals dipping into hot MAPbBr₃ solution as (a) 20 seconds, (b) 50 seconds, (c) 2 minutes, (d) 10 minutes, (e) 1 hours to (f) 4 hours, respectively.

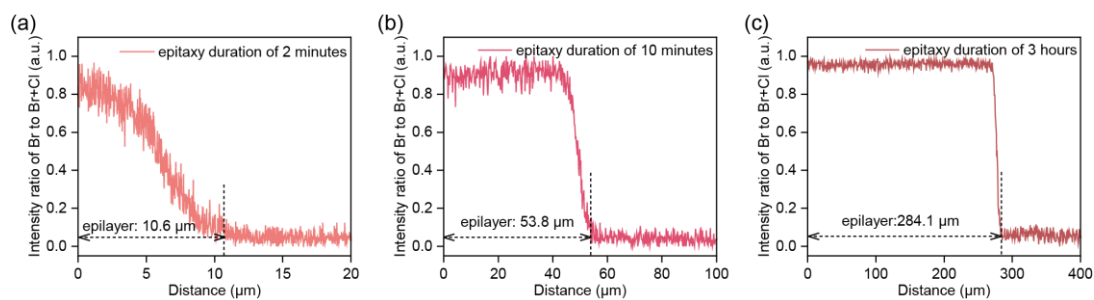


Figure S3 EDX line scanning results images of the Br/(Br+Cl) atom intensity ratio across the epitaxial interface of formed heterojunctions with the duration of MAPbCl₃ crystals dipping into hot MAPbBr₃ solution as (a) 2 minutes, (b) 10 minutes, and (c) 3 hours, respectively.

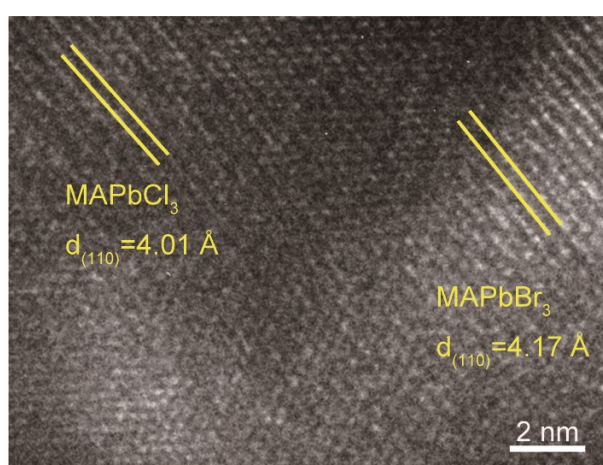


Figure S4 HRTEM image of the interface region of Bi-MAPbCl₃/MAPbBr₃ single-crystalline heterojunction.

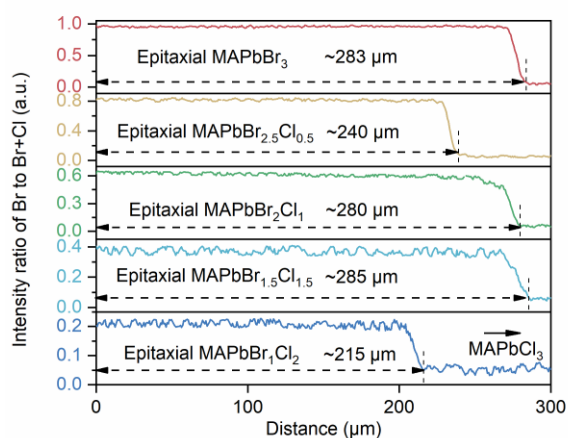


Figure S5 EDX line scanning results images of the Br/(Br+Cl) atom intensity ratio from epitaxial MAPbBr_xCl_{3-x} surface to the MAPbCl₃ substrate.

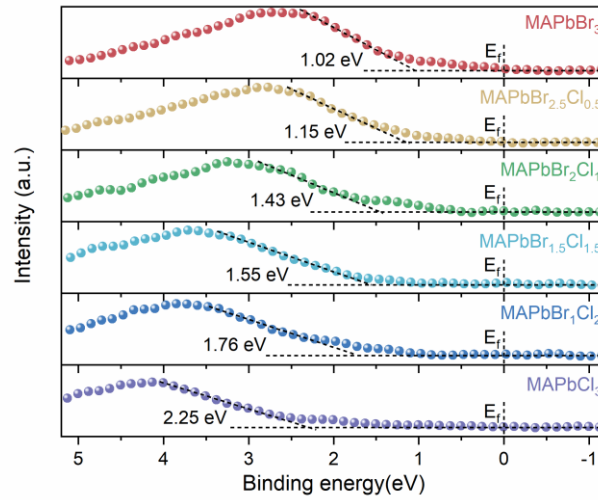


Figure S6 XPS valence spectra of fabricated single-crystalline $\text{MAPbBr}_x\text{Cl}_{3-x}$ samples with $x=0, 1, 1.5, 2, 2.5, 3$, respectively.

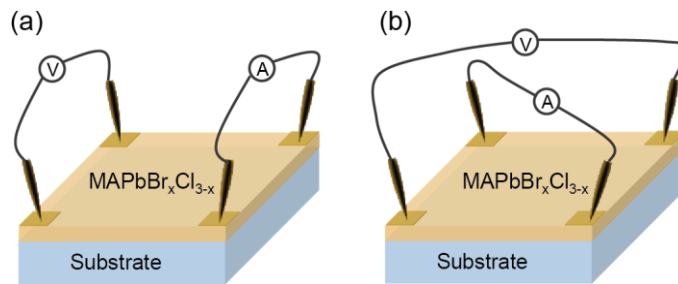


Figure S7 Schematic diagram of (a) sheet resistivity measurement and (b) hall effect measurement for the epitaxial $\text{MAPbBr}_x\text{Cl}_{3-x}$ single-crystalline layers by four contacts van der Pauw method.

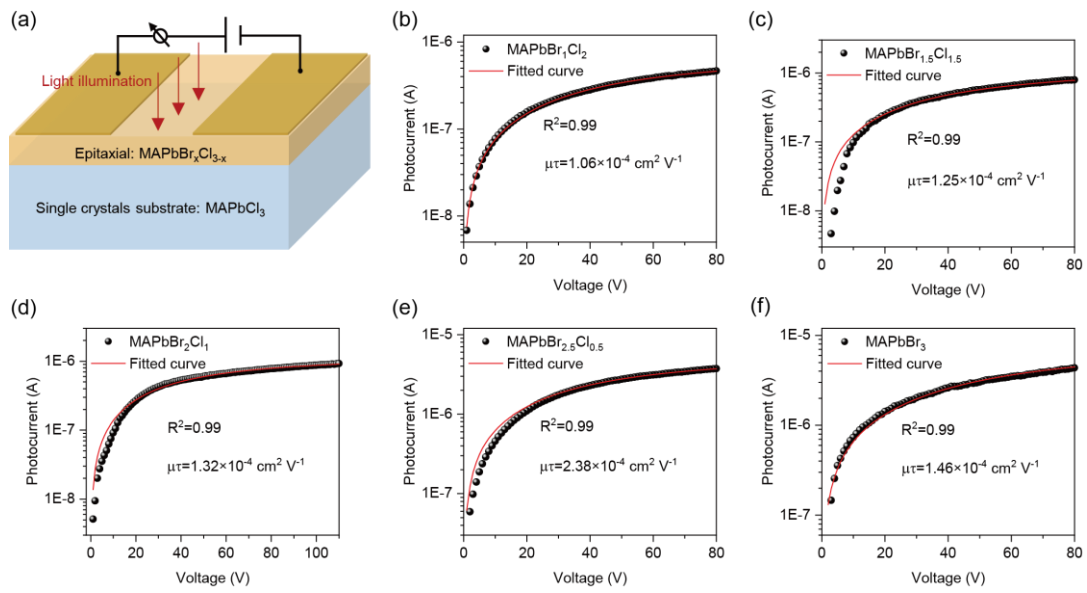


Figure S8 (a) Schematic diagram of the voltage-dependent photocurrent measurement for the epitaxial MAPbBr_xCl_{3-x} single-crystalline planar-type devices. (b-f) The results of voltage-dependent photocurrent for different epitaxial MAPbBr_xCl_{3-x} layers. The red solid line represents a mobility-lifetime fitting to the data according to the Hecht equation.

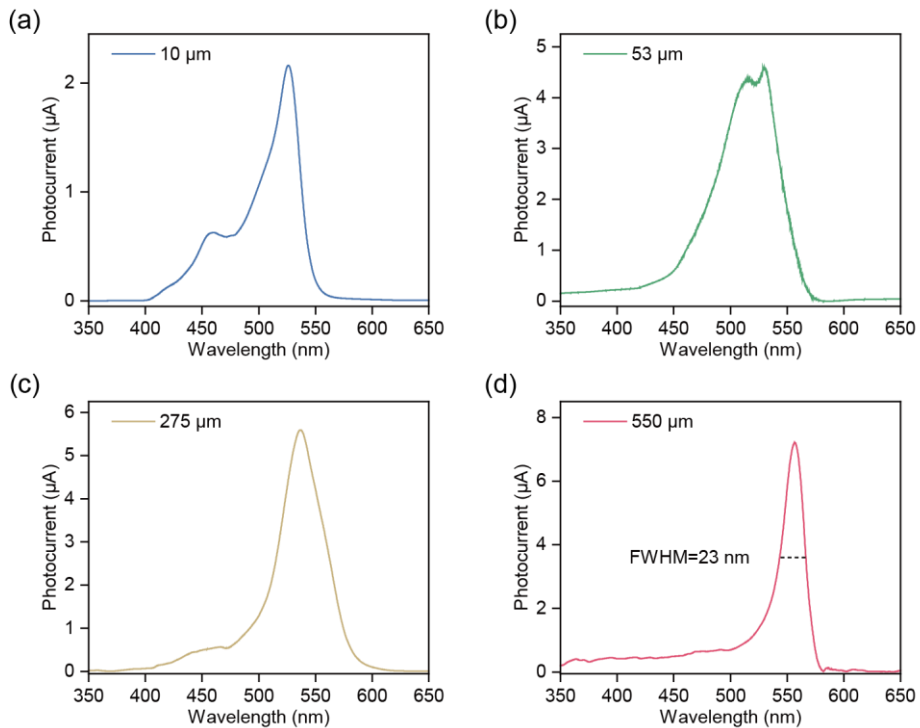


Figure S9 Photo response spectra of the epitaxial planar-type MAPbBr₃ photodetectors with different thickness upon bottom illumination at an external electric field of 30 V mm⁻¹.

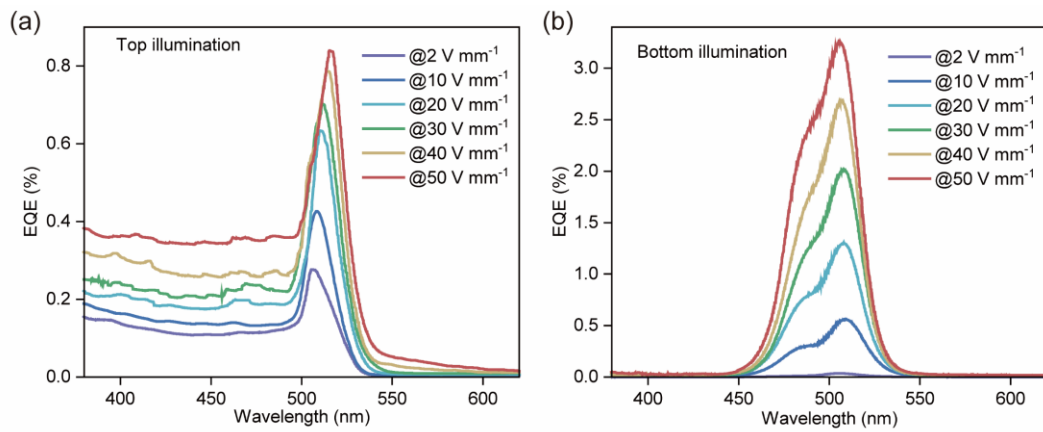


Figure S10 EQE spectra of the planar-type $\text{MAPbBr}_{2.5}\text{Cl}_{0.5}$ photodetector under various external electric field upon (a) top illumination and (b) bottom illumination.

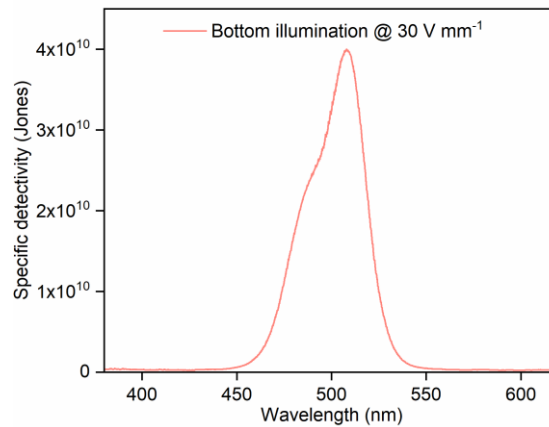


Figure S11 Specific detectivity (D^*) of the planar-type $\text{MAPbBr}_{2.5}\text{Cl}_{0.5}$ photodetector under 30 V mm^{-1} upon bottom illumination.

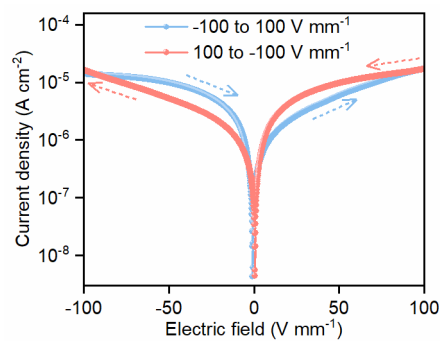


Figure S12 Current density-Electric field hysteresis loop for the epitaxial $\text{MAPbBr}_{2.5}\text{Cl}_{0.5}$ planar-type device in darkness.

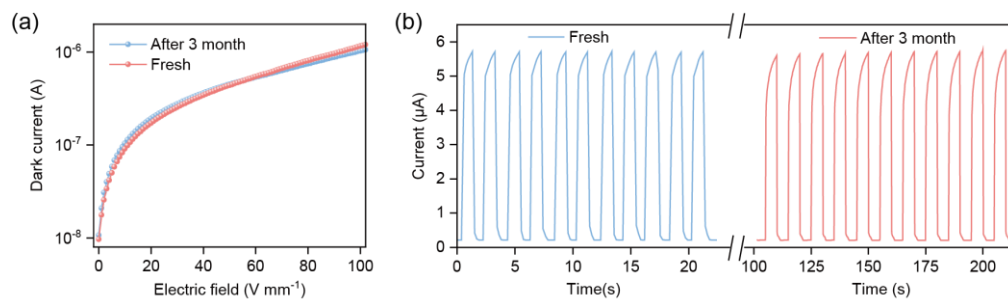


Figure S13 Long-time stability of the epitaxial MAPbBr_{2.5}Cl_{0.5} photodetector: (a) I-V stability in darkness and (b) photo response stability after 3 month in air condition without any encapsulation.

Table S1 The key optoelectronic parameters of MAPbBr_xCl_{3-x} perovskite crystals and films reported in literatures.

Material	Morphology	Mobility (cm² V⁻¹ s⁻¹)	Carrier lifetime (ns)	Diffusion length (μm)	Ref.
MAPbBr_xCl_{3-x}	single-crystalline film	110~213	620~1360	16.6~24.8	This work
MAPbCl ₃	single-crystal	42 ± 9	662	3.0–8.5	1
MAPbCl ₃	single-crystal	26	31	NA	2
MAPbCl ₃	Polycrystalline film	NA	6	NA	2
MAPbBr ₃	single-crystal	81 ± 5	899 ± 127	5.4–14.2	3
MAPbBr ₃	single-crystalline film	60	10–60	1.5–3	4
MAPbBr _{2.94} Cl _{0.06}	single-crystal	560	5000	NA	5
MAPbBr ₃	single-crystalline film	60	189±10	5	6
MAPbBr ₃	single-crystalline film	261.94	60.26	NA	7
MAPbBr ₃	single-crystalline film	40.7(e); 27.3(h)	390	6.4(e); 5.2(h)	8
MAPbBr ₃	Polycrystalline film	0.26	168	0.33	6
MAPbBr ₃	Polycrystalline film	8.6(e); 9.0(h)	51	1.058 ± 0.048	9

Reference

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